

Micro G Switch Bottom Contact Model AT-15-B

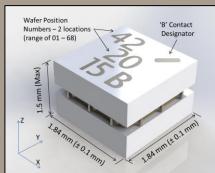
FEATURES:

- Small and Lightweight 3.4 mm²
- Extremely Fast Response Times
- High Shock Survivability 65.000+ of
- Surface Mount Au over Ni Pads
- Tape and Reel Packaging
- Environmental Seal

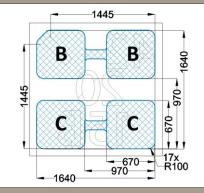
APPLICATIONS:

- Impact Detection
- Arming / Fuzing
- Artillery, Launch
- More





AT-15-B Device Dimensions



AT-15-B Pad Dimensions (micrometers) as viewed from **PAD** side of device

Specifications

OPERATING CHARACTERISTICS:

Sensitivity	+Z (normal to PCB)	
Contact Acceleration Threshold		g
Contact Type (3)		Ü
Response Time (2)		μS
Reset		•
ELECTRICAL CHARACTERISTICS		
Contact Resistance (1)	< 10	ohms
Insulation Resistance		Mohm
Breakdown Voltage		VDC
ENVIRONMENTAL RATINGS:		
Operate Temperature Range	55 to +125	°C
Storage Temperature Range	55 to +125	°C
PCB/Pad Shear Force		N
Shock Survival (4)		g
PHYSICAL CHARACTERISTICS:		
Nominal Dimensions (LxWxH)	1.84 x 1.84 x 1.3	mm
Volume		mm^3
Mass		milligrams
		9. 50

(1) Contact resistance is dependent on input pulse acceleration level.

ROHS Compliant?.....Yes

- Response time depends upon input pulse profile and magnitude. Response time shown is for acceleration step of 60a.
- (3) Electrical connection between pads B (bottom) and C (common) is normally open and is closed while acceleration is greater than the contact acceleration threshold.
- (4) The Micro G Switch devices are designed to survive the extreme high shock environments associated with artillery launch events.

Note that the information on this data sheet is for reference only.

As each application may have unique requirements, please verify the specifications as well as suitability of using our products in your applications by consulting our engineering department.

This product and related technical data are controlled for export by the International Trade in Arms Regulations. Any sale, export, transfer or re-sale, in any form, requires the prior written approval of the U.S. Department of State.

Rev 220602